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M. Khodas and A. Levchenko
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Raman scattering as a probe of nematic correlations

M. Khodas$^{1,2}$ and A. Levchenko$^3$

$^1$Department of Physics and Astronomy, University of Iowa, Iowa City, Iowa 52242, USA  
$^2$Racah Institute of Physics, Hebrew University of Jerusalem, Jerusalem 91904, Israel  
$^3$Department of Physics, University of Wisconsin-Madison, Madison, Wisconsin 53706, USA  

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We use the symmetry constrained low energy effective Hamiltonian of iron based superconductors to study the Raman scattering in the normal state of underdoped iron-based superconductors. The incoming and scattered Raman photons couple directly to orbital fluctuations and indirectly to the spin fluctuations. We computed both couplings within the same low energy model. The symmetry constrained Hamiltonian yields the coupling between the orbital and spin fluctuations of only the same symmetry type. Attraction in $B_{2g}$ symmetry channel was assumed for the system to develop the subleading instability towards the discrete in-plane rotational symmetry breaking, referred to as Ising nematic transition. We find that upon approaching this instability, the Raman spectral function develops a quasi-elastic peak as a function of energy transferred by photons to the crystal. We attribute this low-energy $B_{2g}$ scattering to the critical slow-down associated with the build up of nematic correlations.

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I. INTRODUCTION

The discovery of iron-based superconductors, (FeSCs) opened a new avenues in the research of strongly correlated systems. Despite the diversity in crystallographic structure and chemical composition all the FeSCs share in common several generic trends. FeSCs are multi-band and multi-pocket materials. According to ARPES the Fermi surface (FS) contains two or three hole pockets at the center of the Brillouin zone, $\Gamma$ point, and two electron pockets centered at $(\pi, \pi)$, $M$ point in two iron unit cell notations. The underdoped compounds undergo structural tetragonal to orthorhombic transition at the temperature $T_s$ followed by or coincident with the spin density wave (SDW) transition at $T_{SDW}$. The superconductivity sets in when the magnetism is suppressed by doping or pressure.

The interplay between the magnetism and superconductivity is manifest in the weak coupling renormalization group analysis of competing instabilities. The interaction amplitude in the spin density wave channel is renormalized similar to the usual renormalization in the particle-particle channel that normally leads to Cooper instability. Above the Fermi energy, $E_F$ the two channels affect each other. As a result, the inter-pocket pairing interaction is enhanced by the spin fluctuations which was suggested to drive the unconventional $s^{\pm}$ superconductivity with the order parameter changing sign between the electron and hole FSs. In this picture low (high) doping makes the magnetic (Cooper) instability a winner in a competition at energies below $E_F$. It follows that the proximity of the magnetic and superconducting phases on a phase diagram is not accidental. Hence, the understanding of magnetic and structural transitions is instrumental for the description of the superconductivity.

Most commonly at the magnetic transition the continuous $O(3)$ symmetry and the discrete time reversal symmetry are broken. In the FeSCs the spin alignment is magnetic along one direction and anti-ferromagnetic in the orthogonal direction. Such stripe magnetization lowers, therefore the discrete $C_4$ rotational symmetry of the lattice down to $C_2$. The possibility of breaking the $C_4$ symmetry without breaking the spin $O(3)$ and time reversal symmetry was studied in the context of the structural transition, and the corresponding transition was referred to as Ising nematic. In this picture, below $T_s$ the spin correlation length increases in one of the symmetry directions and decreases in the other, and the magnetisms sets in with little or no delay.

The prevailing scenario of the structural transition is electronic. Specific to FeSCs is rather high degree of $ab$ anisotropy in electronic properties. The resistivity anisotropy $\rho_b/\rho_a$ in cobalt doped BaFe$_2$As$_2$ is reported to reach values as high as 2 for cobalt concentration $x \approx 0.03$ whereas the maximal orthorhombic distortion for the parent material, $x = 0$ is only about 0.36%. Moreover in strain controlled samples the derivative of $(\rho_b - \rho_a)/(\rho_b + \rho_a)$ with respect to the strain shows a divergence at the interpolated mean field temperature $T^* = 116K$ for parent compound. The $T^*$ so obtained is only 22K lower than the actual transition temperature, $T_s = 138K$. The relatively small difference $T_s - T^*$ is due to the lattice fluctuations being suppressed under the conditions of fixed strain. Likewise, the optical reflectivity is nearly divergent at the nematic transition. All these findings are indicative of a dominance of electronic degrees of freedom in the nematic transition.

It is in general hard to disentangle different electronic fluctuations channels breaking the same symmetry. At present the dominance of either charge or spin degrees of freedom in driving the structural transition is not settled. There are two schools of thought as for the origin of electronic nematicity. In orbital nematicity scenario the difference in populations $n_{Xz} - n_{Yz}$ of the $d_{Xz}$
and $d_{Yz}$ iron orbitals is believed to be a primary cause of the nematic transition.\textsuperscript{21–25} In another scenario it is the spin that drives the nematic transition.\textsuperscript{20,26} Let $m_{1,2}$ be the two staggered (antiferromagnetic) magnetizations on the even and odd iron sublattices respectively. The nematic transition occurs when the two spin sublattices lock, $\langle m_1 \cdot m_2 \rangle \neq 0$.\textsuperscript{27} The two alternatives being the positive and negative $\langle m_1 \cdot m_2 \rangle$ resulting in the two orthogonal stripe magnetizations, $\Delta X,Y = m_1 \pm m_2$. These are the spin arrangements ferromagnetic in $X(Y)$ direction and antiferromagnetic in $Y(X)$ direction in Fe only lattice. The magnetic perspective is supported by the NMR spectroscopy kick in far into the paramagnetic phase up to room temperatures. The Raman spectroscopy is essentially dynamic probe of electronic correlations of pre-existing and antiferromagnetic in $X$ and $Y$. The vectors $\hat{x}$ and $\hat{y}$ are chosen as a basis vectors of the two-iron unit cell lattice. (b) The two-iron Brillouin zone. The $\Gamma$ point hosts two hole pockets and the $M$ points hosts two electron pockets. The solid (black) and dashed (blue) lines denote the $d_{xz}$ and $d_{yz}$ orbital contents respectively. The admixture of the $d_{XY}$ orbital at the outer parts of the crossed Fermi pockets at $M$ is neglected. The polarization vectors $e^x$ and $e^y$ for the $B_{2g}$ Raman configuration are shown.

II. RAMAN RESPONSE IN FOUR BAND MODEL

A. Band structure model

In this section we discuss the phenomenological four band model based on the work of Cvetkovic and Vafek.\textsuperscript{36} In this model constructed using the method of invariant due to Luttinger\textsuperscript{37} the interaction of electrons with light is easily obtained by the standard gauge invariant minimal coupling procedure\textsuperscript{35}. Here we neglect the coupling between the different layers and consider the crystal structure as quasi-two-dimensional, see Fig. 1(a). Generically, in FeSCs each layer contains the iron atoms forming a simple square lattice with the basis unit vectors $\hat{x}$ and $\hat{y}$. The pnictogen or chalcogen atoms forming the checkerboard with even and odd sublattices above and below the iron layer. Above the SDW transition the unit cell contains two iron atoms with the basis denoted by $\hat{x}$ and $\hat{y}$.

It is sufficient to consider slightly simplified version of the model\textsuperscript{36} whereby the four dimensional effective Hamiltonian describing the $M$ point is replaced with the two-dimensional one and the remaining electronic bands that are not crossing the Fermi level are discarded. We write for the quadratic part of the Hamiltonian,

$$\mathcal{H} = \sum_{k,\alpha,i,j=1,2} c_{i,k,\alpha}^{\dagger} H_{k_{i,j},\alpha}^{\Gamma} c_{j,k,\alpha} + f_{i,k,\alpha}^{\dagger} H_{k_{i,j},\alpha}^{M} f_{j,k,\alpha},$$

(1)

where $c_{i,k,\alpha}^{\dagger}$ ($f_{i,k,\alpha}^{\dagger}$) creates a hole (an electron) in a state with spin index $\alpha$ and momentum $k$ counted from $\Gamma$ ($M$) point. The index $i = 1 (i = 2)$ refers to the $d_{xz}$ ($d_{yz}$) orbital content. For that reason the Hamiltonian (1) refers to the orbital basis and reads

$$H_{k}^{\Gamma} = \begin{bmatrix} \epsilon_{\Gamma} + \frac{k_{x}^{2}}{2m_{\Gamma}} + ak_{x}k_{y} & \frac{k_{x}^{2} - k_{y}^{2}}{2} \\ \frac{k_{x}^{2} - k_{y}^{2}}{2} & \epsilon_{\Gamma} + \frac{k_{x}^{2}}{2m_{\Gamma}} - ak_{x}k_{y} \end{bmatrix}$$

(2)

for holes, and

$$H_{k}^{M} = \begin{bmatrix} \epsilon_{M} + \frac{k_{x}^{2}}{2m_{M}} + bk_{x}k_{y} & 0 \\ 0 & \epsilon_{M} + \frac{k_{x}^{2}}{2m_{M}} - bk_{x}k_{y} \end{bmatrix}$$

(3)

for electrons. The parameters entering the equations (2) and (3) obtained from the fits to the tight binding calculations\textsuperscript{38,39} are tabulated in Ref. (36). Below we set $a = c$ which corresponds to circular hole FSs. In this work we neglect the spin-orbit coupling and at $\Gamma$, $k = 0$, the two Bloch states are degenerate. The equation (3) neglects the admixture of the $d_{XY}$ orbitals, and the parameter $b$ is the pocket ellipticity.

The Hamiltonians Eqs. (2) and (3) describe the band structure shown in Fig. 1(b). The band structure obtained by diagonalization of these Hamiltonians contains two hole pockets at $\Gamma$ with orbital content alternating between $d_{xz}$ and $d_{yz}$ with $\pi$ periodicity, and two electron pockets at $M$. The electron pockets cross and their outer

FIG. 1: (color online) (a) The unit cell of a quasi-two-dimensional FeSC contains two iron atoms and two pnictogen atoms such as As (or chalcogen atom such as Se). The atoms above and below the iron layer are denoted by crosses and by circles respectively. The basis vectors of the iron-only lattice are denoted by $X$ and $Y$. The vectors $\hat{x}$ and $\hat{y}$ are chosen as a basis vectors of the two-iron unit cell lattice. (b) The two-iron Brillouin zone.
parts contain an admixture of the $d_{xy}$ orbital. Here we neglect such an admixture while preserving the overall symmetry of the Hamiltonian.

### B. Raman coupling

Raman scattering is a two-photon process. Its amplitude contains one part which is second order in the dipolar interaction and the first order in the coupling via the effective mass tensor. Assuming that the base frequency is detuned off the dipole transitions it is customary to ignore the dipolar coupling. Under these circumstances the inelastic Raman scattering cross-section as a function of the retard shift $\omega$ is proportional to the imaginary part of the retarded Raman susceptibility, $\{\kappa_R(q, \omega)\}$

We compute it from the corresponding Matsubara correlation function of the Raman vertices,

$$\kappa(q) = \langle \hat{r} \hat{r} \rangle_q,$$  \hspace{1cm} (4)

where the vector $q = (q, i\omega_m)$ includes the spatial wave vector, $q$ and Matsubara frequency, $\omega_m$, and we denote, $(AB)_q = \int_0^{T-1} d\tau \exp(i\omega_m \tau)(A_q(\tau)B_{-q}(\tau))$. The experimental situation corresponds to $q = 0$ in Eq. (4), and the Raman susceptibility $\kappa_R(0, \omega)$ is obtained from $\kappa(q)$ by setting $q = 0$ and performing the analytical continuation, $i\omega_m \rightarrow \omega$. Below in writing the Matsubara frequency $\omega_m$, we omit the subscript $m$ for brevity.

The expression for the Raman vertices

$$\hat{r} = \sum_{k,\alpha} \sum_{i,j=1,2} c_{i,ka}^\dagger \Gamma_{ij}^{M} c_{j,ka} + f_{i,ka}^\dagger \Gamma_{ij}^{M} f_{j,ka}$$  \hspace{1cm} (5)

is fixed by the Hamiltonian, as formulated by Eqs. (1), (2) and (3), as well as the polarization vectors of incoming and scattered photons, $e^l$ and $e^s$,

$$\Gamma_{ij}^{M} = \sum_{\lambda\sigma} e^l_{\lambda\sigma} e^s_{\lambda\sigma} \frac{\partial^2 \mathcal{H}_0^{\lambda\sigma}}{\partial k_{\lambda} \partial k_{\lambda}^*}.$$  \hspace{1cm} (6)

In this work we focus on the $B_{2g}$ Raman configuration such that polarization vectors of incoming and scattered photons are $e^l = (\hat{X} + \hat{Y})/\sqrt{2} = \hat{x}$, and $e^s = (\hat{Y} - \hat{X})/\sqrt{2} = \hat{y}$, respectively, see Fig. 1. The reason for this is twofold. First, the build up of the low energy $B_{2g}$ Raman intensity upon cooling is the dominant feature observed experimentally above $T_s$. Second, both orbital and the nematic fluctuations have the $B_{2g}$ symmetry. Indeed, Eq. (6) in combination with Eqs. (2) and (3) gives

$$r^l = a \begin{bmatrix} 1 & 0 \\ 0 & -1 \end{bmatrix}, \quad r^M = b \begin{bmatrix} 1 & 0 \\ 0 & -1 \end{bmatrix}. \hspace{1cm} (7)$$

Equation (7) shows that photons in $B_{2g}$ Raman configuration couple directly to orbital fluctuations.

### III. EFFECTIVE ACTION AND RAMAN SUSCEPTIBILITY

We compute the Raman susceptibility as given by Eq. (4) with the Raman vertex specified by Eqs. (5) and (7). In doing so we follow closely the derivation of Ref. (16). To compute the Raman susceptibility we add to the quantum action the source term,

$$S_f = J_\omega \hat{r} - \omega + J_\omega \hat{r} \omega$$  \hspace{1cm} (8)

and the Raman susceptibility, Eq. (4) is obtained by a functional derivative of a free energy functional,

$$\kappa(\omega) = \frac{\delta^2 \mathcal{F}[J]}{\delta J_\omega \delta J_{-\omega}},$$  \hspace{1cm} (9)

computed at $J_\omega = J_{-\omega} = 0$.

Here we focus on the spin interactions for definiteness, and comment on the role of the orbital fluctuations. In the purely magnetic scenario of the nematic transition we write the interaction in the form,

$$\hat{H}_{int} = \frac{1}{2} u_s \sum_q \sum_{i=1,2} s_{i,q} s_{i,-q},$$  \hspace{1cm} (10)

where the spin operators are diagonal in orbital index $i$,

$$s_{i,q} = \sum_k \sum_{i=1,2} c_{k+i,q,\alpha}^\dagger \sigma_{\alpha\beta} f_{k,\beta},$$  \hspace{1cm} (11)

where the $\sigma_{\alpha\beta}$ are the Pauli matrices. The standard Hubbard-Stratonovich transformation amounts to the decoupling of the interaction term, Eq. (10) via the stripe magnetizations, $\Delta^{X,Y} \propto \sum_k c_{k+q,1(2)\alpha}^\dagger \sigma_{\alpha\beta} f_{k,1(2)\beta}$. The integration over fermion operators results in the effective action that closely resembles that of Ref. (16),

$$S[\Delta^{X,Y}, J_{\pm\omega}] = \int_q \chi_q^{-1} (|\Delta^{X}_q|^2 + |\Delta^{Y}_q|^2)$$

$$-\frac{g}{2} [||\Xi_X(0)||^2 + ||\Xi_Y(\omega)||^2] + ||\lambda_{AL} JL\Xi_X(\omega) + c.c.||,$$  \hspace{1cm} (12)

where we introduced the notation

$$\Xi_X(\omega) = \sum_{\Omega,q} [\Delta^{X}_{q+\Omega} \Delta^{X}_{q} - \Delta^{X}_{q} \Delta^{X}_{q+\Omega}],$$  \hspace{1cm} (13)

For $\omega = 0$, Eq. (13) describes the classical contribution of the nematic fluctuations into the Ginzburg-Landau free energy, while $\Xi_X(\omega)$ describes the quantum nematic fluctuation driven by the external source at the same frequency.

We now comment on Eq. (12). First, we omitted the term $\propto (|\Delta^{X}|^2 + |\Delta^{Y}|^2)^2$ responsible for the renormalization of the spin susceptibility $\chi_{\alpha}$, and crucially important for the nature of the magnetic and structural
transition. Here we are not concerned neither with the feedback of nematic fluctuations on magnetism, nor with the mapping out the phase diagram, and for that reason do not include this term in the action keeping the spin susceptibility renormalized.

Second, the last term in Eq. (12) describes the coupling of the Raman vertex to the spin nematic order parameter \( \propto (\Delta X)^2 - (\Delta Y)^2 \) via the triangular Aslamazov-Larkin like vertex, \( \lambda_{AL} \) evaluated in the App. A. We have shown this vertex can be approximated by a frequency and momentum independent function. Most relevant for the present analysis is the weak temperature dependence of \( \lambda_{AL} \) for temperatures exceeding the mismatch between the electron and hole Fermi surfaces. As the latter can be few tens of meVs the above statements hold for most of the relevant temperatures.

We further perform the second Hubbard-Stratonovich transformation by introducing the nematic field \( \phi_0 \). Corresponding to the two terms quartic in \( \Delta X(Y) \) in Eq. (12) we introduce the static nematic field \( \phi_0 \) and the quantum time dependent nematic field \( \phi(\tau) = \phi_0 e^{i\omega\tau} \). The resulting quadratic action reads,

\[
S = \sum_q \left( (\chi_q^{-1} + \phi_0) |\Delta X_q|^2 + (\chi_q^{-1} - \phi_0) |\Delta Y_q|^2 \right.
\]

\[
+ \left[ (\phi_{-\omega} + \lambda_{AL} J_{-\omega}) \Xi_{XY}(\omega) + c.c. \right] \frac{\phi_0^2}{2g} + \left| \frac{\phi_0}{g} \right|^2.
\]

The action (14) is quadratic with respect to the stripe order parameters, which thus can be integrated out explicitly. This procedure results in the effective action,

\[
\exp(-\mathcal{F}) = \int d\Delta X d\Delta Y \exp(-S) = \exp \left( \frac{\phi_0^2}{2g} - \frac{|\phi_0|^2}{g} \right) \det(D^1) \det(D^3),
\]

where we have defined matrices in the Fourier space

\[
\hat{D}_\pm = \hat{\chi}_\pm^{-1} \pm (\phi_{-\omega} + \lambda_{AL} J_{-\omega}) \hat{M}_\pm \pm (\phi_0 + \lambda_{AL} J_0) \hat{M}_0,
\]

with \( \hat{\chi}_\pm^{-1} = \delta_{q_1, q_2, \omega_1, \omega_2} (\chi_{q_1}^{-1} \pm \phi_0) \) and \( \hat{M}_\pm = \delta_{q_1, q_2, \omega_1, \omega_2} \pm \omega \). With the help of the standard formula we convert determinant into the trace of the logarithm, \( \det\hat{D} = \exp(\text{Tr} \ln \hat{D}) \), and expand the resulting effective action up to the second order in the nematic fields and the source strength. Such an expansion amounts to the mean field approximation that can be justified in the large \( N \) limit. In Ref. (16) the thermodynamic properties of the same model were shown to be reasonably well captured in this approximation for \( N = 3 \) and we employ it here as well, and write

\[
\mathcal{F} = \frac{\phi_0^2}{2g} + \frac{|\phi_0|^2}{g} - 3\phi_0^2 \Upsilon(0) - 3 |(\phi_0 + \lambda_{AL} J_0)|^2 \Upsilon(\omega),
\]

(17)

\[
\Upsilon(\omega) = 3 |\lambda_{AL}|^2 \frac{\Upsilon(\omega)}{1 - 3 g \Upsilon(\omega)},
\]

(18)

has been introduced.

The action (17) is quadratic and the functional derivative in Eq. (9) gives for the Raman susceptibility,

\[
\kappa(\omega) = 3 |\lambda_{AL}|^2 \Upsilon(\omega),
\]

(19)

see Fig. (2) for diagrammatic representation. To compute \( \Upsilon(\omega) \) we use the standard finite temperature Matsubara summation technique over the discrete frequencies followed by an analytic continuation to the real axis, \( i\omega_n \to \omega + i0 \), to obtain the retarded spin nematic correlation function \( \Upsilon(i\omega_n) \to \Upsilon_R(\omega) \).

To this end, we evaluate the bare susceptibility (18) by converting the Matsubara sum over \( \Omega \) into the complex integral

\[
\Upsilon(i\omega_n) = \sum_q \int dz e^{-iz} \chi(q, \omega + i0) \chi(q, \omega + \Omega).
\]

(20)

The integrand has two branch cuts at \( \Im(z + i\omega_n) = 0 \) and \( \Im(z) = 0 \) where the product of two \( \chi \) functions has breaks of analyticity. As a result of analytic continuation process we get

\[
\Upsilon(\omega) = \sum_q \int d\Omega e^{-iz} \chi_R(q, \Omega) \chi(q, \Omega + \omega)
\]

(21)

To make further progress we use standard expression for the spin correlation function \( \chi(q, \Omega) \),

\[
\chi(q, \Omega_m) = \frac{c}{\xi^{-2} + (Q - q)^2 + |\Omega_m|/\gamma},
\]

(22)
where the important scale is
\[ \frac{1}{\tau_s} = \frac{\gamma}{\xi^2} \]  
(23)
and \( Q = (\pi, \pi) \). Separating the real and imaginary components one finds
\[ \text{Im} \chi^R(q + Q, \Omega) = \chi'' = \frac{\Omega \tau_s}{(1 + q^2 \xi^2)^2 + \Omega^2 \tau_s^2}, \]  
(24)
\[ \text{Re} \chi^R(q + Q, \Omega) = \chi' = \frac{1 + q^2 \xi^2}{(1 + q^2 \xi^2)^2 + \Omega^2 \tau_s^2}. \]  
(25)
The symmetry between the two stripe-like spin ordering arrangements is broken at the Ising-nematic type transition. Here we assume the mean field critical exponent \( \nu = 1/2 \), i.e.
\[ \xi(T) \approx l \sqrt{T_N/(T - T_N)} \]  
(26)
with \( T_N \) being the mean field SDW transition temperature, and \( l \) a microscopic length scale. We emphasize that the mean field transition temperature can be substantially lower than the observed SDW transition temperature, \( T_N < T_{SDW} \). Eq. (22) also shows that the critical behavior of the static susceptibility, \( \chi(Q_m = 0, Q) = \xi^2/2 \propto (T - T_N)^{-1} \) is as prescribed by the mean field too.

We proceed by substituting (24) and (25) into the general relation (21) to get for the imaginary part of the susceptibility
\[ \Upsilon''(\omega) = \gamma \int_0^\infty \frac{dx}{2\pi} \int_{-\omega}^{\omega} \frac{dy}{2\pi} \coth(y/2t) \]  
\[ \times \frac{y + w}{(1 + x)^2 + (y + w)^2} - \frac{y - w}{(1 + x)^2 + (y - w)^2}. \]  
(27)
Here we introduced dimensionless variables \( x = (q\xi)^2, y = \Omega \tau_s, t = T \tau_s, \) and \( w = \omega \tau_s \). The above expression is general. In a view of Raman experiments, below we consider in details the limiting case of high-temperatures, \( T \tau_s \gg 1 \), that corresponds to the regime of essentially classical fluctuations.

In the classical region when \( t \gg 1 \), assuming also not too high frequencies, \( T > \omega \), one can approximate \( \coth(y/2t) \approx 2t/y \). The double integral in Eq. (27) can be then evaluated analytically
\[ \Upsilon''(\omega) = \frac{4T^2}{\omega} \ln \left[ 1 + \left( \frac{\omega \xi^2}{2\gamma} \right)^2 \right]. \]  
(28)
Since the integral decays at a scale \( \sim 4\tau_s \), the approximation made should be reasonable for all the frequencies. Similarly we evaluate the real part of susceptibility
\[ \Upsilon'(\omega) = 2\tau_s^{-1} \xi^2 \int_0^\infty \frac{dx}{4\pi} \int_{-\omega}^{\omega} \frac{dy}{2\pi} \coth(y/2t) \]  
\[ \times \frac{1}{(1 + x)^2 + y^2} \frac{1 + x}{(1 + x)^2 + (y + w)^2}. \]  
(29)
The integral in Eq. (29) is logarithmically divergent at ultraviolet. We therefore isolate the divergence in Eq. (29) by focusing first on a static limit \( \omega = 0 \). Then the difference is well convergent and can be easily evaluated as
\[ \Upsilon'(0) = \Upsilon'(0) - \frac{\gamma}{16\pi} \arctan(\omega \tau_s/2). \]  
(30)
To evaluate the static susceptibility \( \Upsilon'(0) \) we split the \( y \)-integration range in Eq. (29) in two regions, \( y < t \) and \( t < y < \Lambda \tau_s \), where the scale \( \Lambda \) is the ultraviolet cutoff. Making approximations \( \coth(y/2t) \approx 2t/y \) and \( \coth(y/2t) \approx \text{sgn}(y) \) in the two respective intervals the resulting integrals can be easily evaluated with the result
\[ \Upsilon'(0) \approx \frac{T^2}{2\pi^2} \arctan(T \tau_s) + \frac{\tau_s^{-1} \xi^2}{4\pi^2} \ln \frac{\Lambda}{T}. \]  
(31)
where arctangent can be further safely approximated by \( \pi/2 \). With these results at hand we find from Eq. (19) for the imaginary part of Raman susceptibility
\[ \kappa''(\omega) = \frac{3 \lambda^2 \gamma^2}{R^2(\omega, \tau) + (4\pi^2 \gamma^2)^2 I^2(\omega, \tau)}. \]  
(32)
Here we have introduced dimensionless frequency \( \omega/\omega = \omega/T_N \) and temperature \( \tau = T/T_N \), and also two dimensionless functions
\[ I(\omega, \tau) = \frac{\tau}{\omega} \ln \left[ 1 + \left( \frac{\omega}{2\pi \tau(\tau - 1)} \right)^2 \right], \]  
(33)
\[ R(\omega, \tau) = 1 - \tilde{g} \frac{\tau}{\tau - 1} + \frac{\gamma L}{\tau - 1} - \frac{\pi \gamma}{4} \arctan \left( \frac{\omega}{2\pi \gamma(\tau - 1)} \right) \]  
(34)
where renormalized coupling \( \tilde{g} = 3gT_N l^2/4\pi \), decay rate \( \gamma = \gamma/\pi T_N l^2 \) and cutoff \( L = \ln(\Lambda/T) \) should be used as a fitting parameters, see Fig. (3) for results. The most prominent feature of our results is the critical enhancement of the Raman susceptibility upon approaching the structural transition with the characteristic build up of the quasi-elastic scattering.

IV. CONCLUSIONS

In this paper we investigated theoretically the low energy Raman scattering in underdoped FeSCs. The gross feature of the data is the quasi-elastic peak that gains in intensity and softens down at cooling above the structural transition. The phenomenon is observed exclusively in \( B_{2g} \) Raman geometry. The Lorentzian-like frequency dependence of the \( B_{2g} \) Raman susceptibility describes the relaxation dynamics with the relaxation rate given by the position of the maximum. The temperature dependence of the susceptibility indicates the freezing of the electronic \( B_{2g} \) fluctuations at cooling. Such behavior is naturally associated with the tendency to long range order which breaks the \( B_{2g} \) symmetry. I.e. the broad
recently in Ref. 42. These fluctuations add to the static correlations and the orthorhombic lattice vibrations studied in terms of the coupling of the electron nematic fluctuations related to the C\textsubscript{4} rotation for increasingly longer time intervals.

To understand the origin of quasi-elastic peak as it appears in Eq. (19) note first that in the static limit the real part of Raman susceptibility scales as $\sim (T - \theta)^{-1}$. The temperature scale $\theta < T_s$ which can be explained in terms of the coupling of the electron nematic fluctuations and the orthorhombic lattice vibrations studied recently in Ref. 42. These fluctuations add to the static nematic coupling constant, $g_{st} = g + \gamma^2 / C_\nu$,\textsuperscript{43,44} The static coupling $g_{st}$ determines $T_s$. Crucially, however it is the dynamic rather than static nematic coupling constant $g < g_{st}$ that defines $\theta$, since the lattice response function has different static and dynamic limits\textsuperscript{45}. Correspondingly, the difference $T_s - \theta$ is expected to correlate with the reduction of $T_s$ in strained control samples\textsuperscript{18}. This is indeed reported to be the case in the recent measurements\textsuperscript{46}. Distinguishing between the two contributions remains a challenge. Nevertheless we can deduce the low energy scattering by making the reasonable assumption on the imaginary part of the bare response. Assume that at low frequencies it scales as $\sim \omega / \Gamma$ with $\Gamma$ being a non-critical at $T = \theta$ and hence weakly temperature dependent relaxation rate. Then it follows from the denominator structure of Eq. (19) that at low frequencies $\kappa''(\omega) \sim (T - \theta + i\omega / \Gamma)^{-1}$ We thus see that the relaxation rate is suppressed by a factor of $T - \theta$ compared to the bare rate $\Gamma$. We conclude that the quasi-elastic scattering is the case of critical slowing down.

Regardless of the origin of the attraction the intra-band processes alone are insufficient to describe the large frequency width of the quasi-elastic scattering. Indeed, at zero momentum such transitions are forbidden and the quasi-elastic peak is absent\textsuperscript{47,48}. The small momentum intra-band transitions restricted to either $\Gamma$ or $M$ points are gapped and cannot account for quasi-elastic scattering either. The excitation of two electron hole pairs at momentum close to the antiferromagnetic wave vector each enables the relaxation of zero momentum excitations by lifting the kinematical constrains. It was argued, however that the phase space limitations make the contributions of such processes to the relaxation rate scale as cubic power of the frequency difference of scattered and incoming photons.\textsuperscript{48} As our calculations demonstrate this suppression is only relevant at very low frequencies and for relevant temperatures and frequencies the scaling is essentially linear. In that regard this situation is very similar to that in cuprates.\textsuperscript{49} Even though the latter are single- rather than multi-band materials the processes that matter the most are confined to the vicinity of hot spots, i.e. the points on a FS connected by the antiferromagnetic wave vector.

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Appendix A: Derivation of the effective action in terms of the stripe magnetizations

The calculations in this section are an extension of the corresponding derivations in Re. (16). We introduce the eight component spinor,

$$\Psi^\dag_k = \left( c^\dag_{1,k\uparrow}; c^\dag_{2,k\uparrow}; f^\dag_{1,k\uparrow}; f^\dag_{2,k\uparrow}; c^\dag_{1,k\downarrow}; c^\dag_{2,k\downarrow}; f^\dag_{1,k\downarrow}; f^\dag_{2,k\downarrow} \right)$$

(A1)
in the direct product of orbital and spin spaces. Upon the introduction of the stripe magnetizations, $\Delta^{X,Y}$ via the Hubbard-Stratonovich transformation the action takes the form,

$$S[\Psi, \Delta^X, \Delta^Y, J_\omega, J_{-\omega}] = - \int \Psi_k^{\dagger} \Gamma^{-1}_{k,k'} \Psi_{k'} + \frac{2}{u_a} \int_q \left[ |\Delta^X(q)|^2 + |\Delta^Y(q)|^2 \right],$$  \hfill (A2)

where we denote $k = (k, i\epsilon)$, and the Green’s function is

$$\mathcal{G}^{-1} = \mathcal{G}_0^{-1} - \mathcal{V},$$  \hfill (A3)

where

$$\mathcal{V} = \mathcal{V}^{\Delta} - \mathcal{V}^{J_{\omega}} - \mathcal{V}^{J_{-\omega}}.$$  \hfill (A4)

The free Green’s function in Eq. (A3) is

$$\mathcal{G}_{0; k, k'} = \delta_{k,k'} \left[ \mathcal{G}^r_{k,e} \begin{array}{rr} 0 & 0 \\ 0 & \mathcal{G}^m_{k,e} \end{array} \right] \otimes \mathbb{I},$$  \hfill (A5)

where the two hole and electron Green’s functions are two dimensional matrices expressed in a standard way,

$$\mathcal{G}^{r,M}_{k,e} = \left( i\epsilon - \mathcal{V}^{r,M}_{k,e} + E_F \right)^{-1}$$  \hfill (A6)

through the hole and electron Hamiltonians Eqs. (2), (3) with energies counted relative to the Fermi level. We further have,

$$\mathcal{V}^{\Delta}_{k,k'} = - \int_q \delta_{k+q,k'} \left[ \begin{array}{rr} 0 & \Delta^X(q) \\ 0 & 0 \\ \Delta^X(q) & 0 \\ 0 & \Delta^Y(q) \end{array} \right] \otimes \sigma.$$  \hfill (A7)

The source term according to Eqs. (5) and (8) reads,

$$\mathcal{V}^{J_{\pm\omega}}_{k,k'} = J_{\pm\omega} \delta_{k,k'} \delta_{e; \pm\omega,e} \left[ \begin{array}{rr} r^r & 0 \\ 0 & -r^m \end{array} \right] \otimes \mathbb{I}$$

with the two dimensional matrices $r^{r,M}$ are defined by Eq. (7). In the presence of the source, (A8) it is necessary to keep the term of the third order in $\mathcal{V}$ in the expansion of the free energy,

$$S[\Delta^X, \Delta^Y, J_\omega, J_{-\omega}] = \frac{1}{2} \text{Tr} (\mathcal{G}_0 V)^2 + \frac{1}{3} \text{Tr} (\mathcal{G}_0 V)^3 + \frac{1}{4} \text{Tr} (\mathcal{G}_0 V)^4 + \frac{2}{u_a} \int_q \left[ |\Delta^X(q)|^2 + |\Delta^Y(q)|^2 \right]$$  \hfill (A9)

of prime interest for us in this work. While even order terms in Eq. (A9) were considered in details in the work Ref. (16), here we focus on the third order term of Eq. (A9). We specifically determine the contribution to the effective action that is linear in the sources $J_{\pm\omega}$ and quadratic in $\Delta^{X,Y}$. Such terms have the form,

$$\text{Tr} (V^{J_{\pm\omega}} \mathcal{G}_0 V^{\Delta} \mathcal{G}_0 V^{\Delta} \mathcal{G}_0) = a J_{\pm\omega} \sum_{\ell} \text{Tr} \left\{ \begin{array}{rr} 1 & 0 \\ 0 & -1 \end{array} \right\} \mathcal{G}^r_{k+q,\pm\omega,;} \mathcal{G}^m_{k,\pm\omega,;} \mathcal{G}^r_{k,-\pm\omega,;} \mathcal{G}^m_{k,-\pm\omega,;} \mathcal{G}^r_{k,;}$$

$$\mathcal{G}^m_{k,;} + c.c.$$  \hfill (A10)

In obtaining Eq. (A10) we used the explicit form, Eq. (7) of the Raman vertices $r^{r,M}$, the block diagonal structure of all the three matrices given by Eqs. (A5), (A7) and (A8). Furthermore the trace operation over the spin indices results in a summation over the Cartesian coordinates of the vectors of the stripe magnetizations, $\Delta^{X,Y}$ labeled by the index $\ell = x, y, z$. The trace operation in Eq. (A10) includes in addition to the usual trace of the two-dimensional matrices, the summation over fermion frequencies and momenta $(i\epsilon, k)$ and boson frequencies and momenta $(i\Omega, q)$.

The integral of Eq. (A10) over the fermion frequencies and momenta is convergent at the upper limit. As a result assuming that the Fermi energy is much larger than the typical energy carried by the magnetic fluctuation, we can neglect the boson momenta and frequency, $\mathbf{q}$ and $\Omega$ in the arguments of fermion Green functions. Furthermore, since
the energy splitting of electronic bands is normally smaller than the Fermi energy we can neglect it and approximate the hole Hamiltonian by a scalar function. In terms of Green function we have

\[ G_{k,e}^{\pi} \approx G_{k,e}^{\Delta} = (i\epsilon - \xi_h)^{-1}, \] (A11)

where \( \xi_h \) is the energy of the hole band relative to the Fermi energy with splitting neglected. Similarly, by neglecting the ellipticity related energy that is small on the scale of the Fermi energy we arrive at the scalar Green function for electrons,

\[ G_{k,e}^{M} \approx G_{k,e} = (i\epsilon - \xi_e)^{-1}, \] (A12)

where \( \xi_e \) is the energy of the electron bands relative to the Fermi energy with ellipticity neglected. Clearly, the above approximations make the corresponding Green’s function denoted by \( G_{k,e}^{\pi} \) and \( G_{k,e}^{M} \) scalar and allow us to rewrite Eq. (A11) as

\[ \text{Tr}(\psi^{J_{\pm\omega}}\psi^{\Delta}\psi^{0}\psi^{\Delta}\psi^{0}) \approx J_{\pm\omega}\Xi_{XY}(\pm\omega) \int_k \left[ a \left( G_{k,e}^{\pi} \right)^2 G_{k,e}^{M} + b \left( G_{k,e}^{M} \right)^2 G_{k,e}^{\pi} \right]. \] (A13)

Identifying the last term of Eq. (12) with Eq. (A13) we finally arrive at the expression for the triangular vertex,

\[ \lambda_{AL} = \int_k \left[ a \left( G_{k,e}^{\pi} \right)^2 G_{k,e}^{M} + b \left( G_{k,e}^{M} \right)^2 G_{k,e}^{\pi} \right], \] (A14)

where the expression for \( \Xi_{XY}(\omega) \) is given in Eq. (13). For definiteness, we evaluate the first term \( \propto a \) in the expression Eq. (A14). For simplicity we assume \( \xi_h = -\xi_e + \delta_{eh} = \xi \), and take the density of states to be a constant \( n_0 \) for both electrons and holes. Under these assumptions the substitution of the Green’s functions in Eqs. (A11) and (A12) in Eq. (A14), followed by the integration over \( \xi \) yields,

\[ \int_k \left( G_{k,e}^{\pi} \right)^2 G_{k,e}^{M} = 2\pi T n_0 \sum_{\epsilon > 0} \left[ \frac{1}{2i\epsilon_n + \delta_{eh}} - \frac{1}{2i\epsilon_n - \delta_{eh}} \right]^2 \] (A15)

As the Matsubara frequencies are of the form, \( \epsilon_n = 2\pi(n + 1/2)T \) we obtain from Eq. (A15),

\[ \int_k \left( G_{k,e}^{\pi} \right)^2 G_{k,e}^{M} = \frac{n_0}{\pi T} \text{Im} \left[ \psi' \left( \frac{1}{2} - i\frac{\delta_{eh}}{2\pi T} \right) \right], \] (A16)

where \( \psi'(x) \) is the derivative of the digamma function. Expression similar to Eq. (A16) holds for the contribution of coupling of light to electrons, and we obtain,

\[ \lambda_{AL} = (a + b) \frac{n_0}{\pi T} \text{Im} \left[ \psi' \left( \frac{1}{2} - i\frac{\delta_{eh}}{2\pi T} \right) \right]. \] (A17)

We note that the contributions of electrons and holes are additive. As typically \( \delta_{eh} \) is few tens of meVs we expect an inequality \( T \lesssim \delta_{eh} \) to hold. As the asymptotic expansion \( \text{Im}[\psi'(1/2 - ix)] \approx 1/x \) holds already for \( x \gtrsim 0.25 \) we can write for the Aslamazov-Larkin vertex,

\[ \lambda_{AL} \approx (a + b) \frac{2n_0}{\delta_{eh}}. \] (A18)

We conclude, that the \( \lambda_{AL} \) is insensitive to the temperature variation in the relevant temperature range, and is suppressed with increasing mismatch between the hole and electron Fermi surfaces. This result is in agreement with the alternative calculation for a different model.45

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